

XP05501 (XP5501)

Silicon NPN epitaxial planar type

For general amplification

■ Features

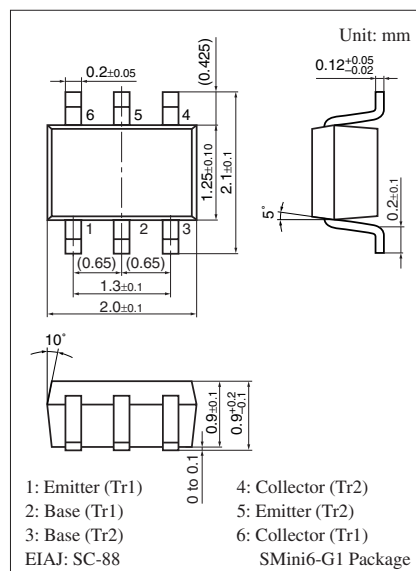
- Two elements incorporated into one package
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number

- 2SD0601A (2SD601A) × 2

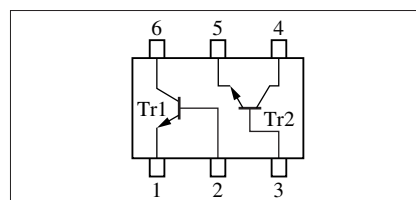
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|-----------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | 60 | V |
| Collector-emitter voltage (Base open) | V_{CEO} | 50 | V |
| Emitter-base voltage (Collector open) | V_{EBO} | 7 | V |
| Collector current | I_C | 100 | mA |
| Peak collector current | I_{CP} | 200 | mA |
| Total power dissipation | P_T | 150 | mW |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |



Marking Symbol: 5L

Internal Connection



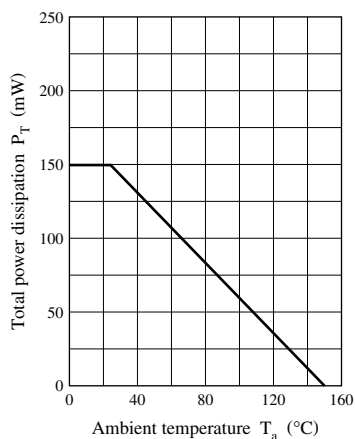
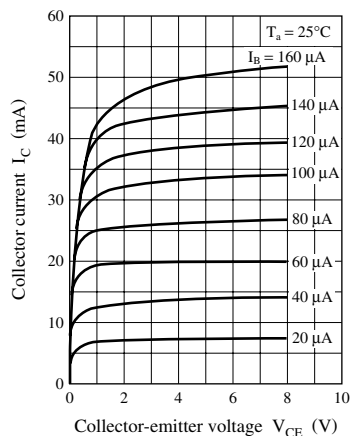
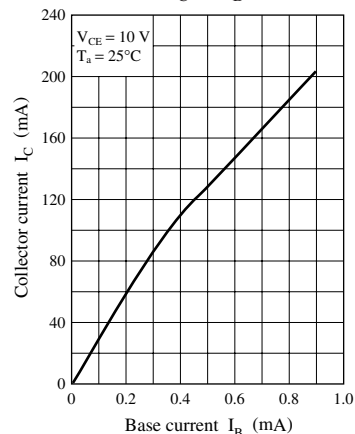
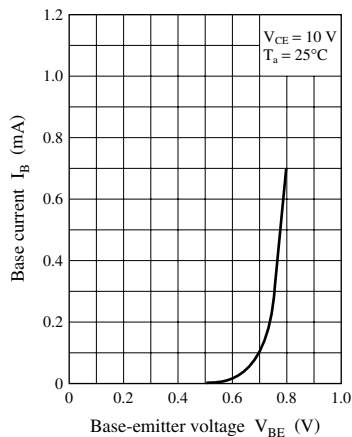
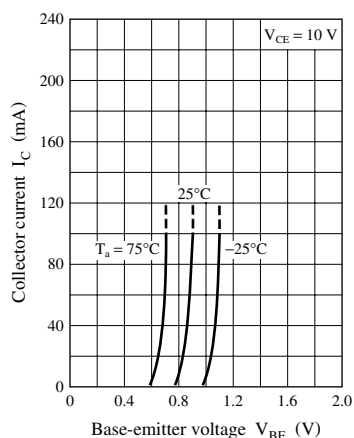
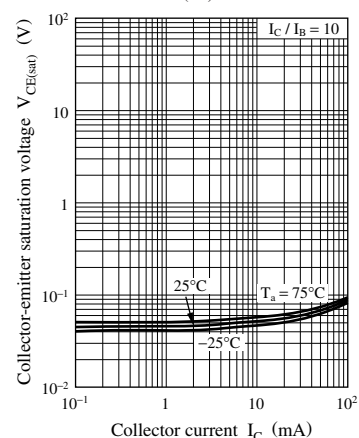
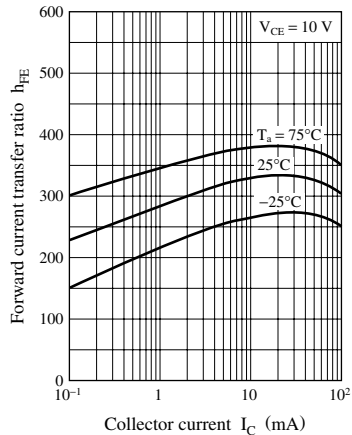
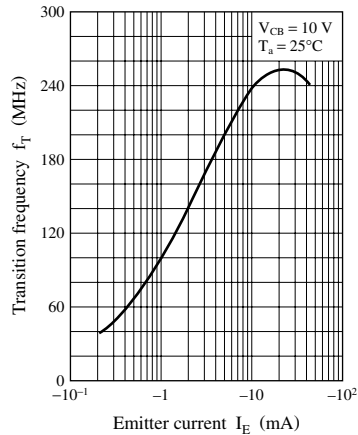
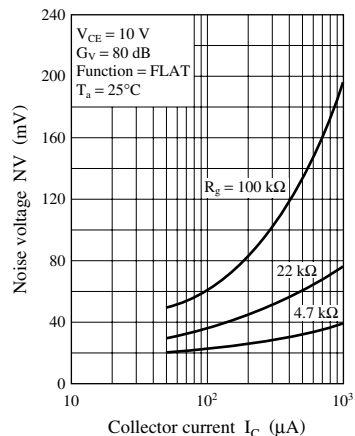
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|------------------------------|---|------|------|-----|---------------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = 10 \mu\text{A}$, $I_E = 0$ | 60 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_C = 2 \text{ mA}$, $I_B = 0$ | 50 | | | V |
| Emitter-base voltage (Collector open) | V_{EBO} | $I_E = 10 \mu\text{A}$, $I_C = 0$ | 7 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = 20 \text{ V}$, $I_E = 0$ | | | 0.1 | μA |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{CE} = 10 \text{ V}$, $I_B = 0$ | | | 100 | μA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10 \text{ V}$, $I_C = 2 \text{ mA}$ | 160 | | 460 | — |
| h_{FE} ratio * | $h_{FE(\text{Small/Large})}$ | $V_{CE} = 10 \text{ V}$, $I_C = 2 \text{ mA}$ | 0.50 | 0.99 | | — |
| Collector-emitter saturation voltage | $V_{CE(\text{sat})}$ | $I_C = 100 \text{ mA}$, $I_B = 10 \text{ mA}$ | | | 0.3 | V |
| Transition frequency | f_T | $V_{CB} = 10 \text{ V}$, $I_E = -2 \text{ mA}$, $f = 200 \text{ MHz}$ | | 150 | | MHz |
| Collector output capacitance (Common base, input open circuited) | C_{ob} | $V_{CB} = 10 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$ | | 3.5 | | pF |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Ratio between 2 elements

Note) The part number in the parenthesis shows conventional part number.

$P_T - T_a$  $I_C - V_{CE}$  $I_C - I_B$  $I_B - V_{BE}$  $I_C - V_{BE}$  $V_{CE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $NV - I_C$ 

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